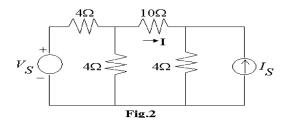
#### Q.2 a. State Superposition Theorem.

Answer: Page Number 484 of Text Book.

b. In the circuit shown below, determine (i) I (ii) find  $I_S$  for  $V_S = 16V$ and I=0 (iii) find  $V_S$  for  $I_S = 16 A$  and I = 0



Answer: Page Number 484 of Text Book.

c. Define the terms (i) Node (ii) Branch (iii) Loop (iv) Mesh and write the procedure for writing nodal equations.

Answer: Page Number 480-481 of Text Book.

# Q.3 a. Explain about n-type doping and p-type doping.

Answer: Page Number 10-11 of Text Book.

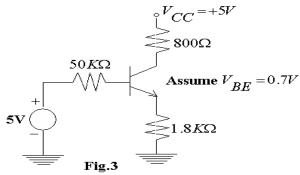
#### b. Explain PN junction behaviour under forward and reverse bias.

Answer: Page Number 14-16 of Text Book.

#### Q.4 a. Explain the operating of PNP transistor.

Answer: Page Number 81-82 of Text Book.

b. For the transistor circuit shown below, calculate  $I_C$ ,  $I_E$  and  $I_B$ , if the transistor's  $\beta = 50$ .



Answer: Page Number 91 of Text Book.

# Q.5 a. Explain h-parameter model of an amplifying device and draw h-parameter models of BJT.

Answer: Page Number 142-144 of Text Book.

#### b. Discuss the BJT biasing circuit with voltage feedback.

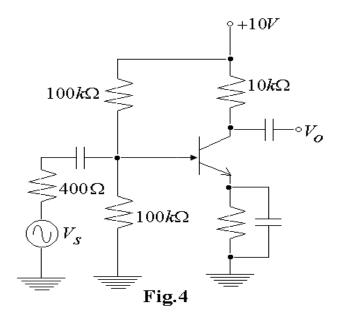
Answer: Page Number 157-158 of Text Book.

#### Q.6 a. Explain the mid-frequency response of RC coupled amplifier.

Answer: Page Number 218-220 of Text Book.

# b. In the BJT RC-coupled amplifier of Fig.4 determine:

(i)  $V_o$  for  $V_s = 5mV$  (ii)  $R_{in}$  and (iii)  $R_{out}$  in the mid-frequency region. Given  $r_{\pi} = 600\Omega, \beta = 100.$ 



Answer: Page Number 220-221 of Text Book.

# Q.7 a. Explain the working of Class B transformer coupled push-pull amplifier and derive the expression for its efficiency.

Answer: Page Number 292-294 of Text Book.

b. Explain Crossover distortion in the push-pull operation of Class B amplifier.

Answer: Page Number 305-326 of Text Book.

#### Q.8 a. Explain the effect of feedback on impedances.

Answer: Page Number 324-325 of Text Book.

**b.** Draw the circuit of Wien bridge oscillator and derive the expression for its frequency of oscillation.

Answer: Page Number 338-339 of Text Book.

# Q.9 a. Explain the following processes in IC fabrication

(i) Diffusion (ii) Ion implantation

Answer: Page Number 450-451of Text Book.

# b. Explain the fabrication of NMOS enhancement type MOSFET.

Answer: Page Number 459-460 of Text Book.

# TEXT BOOK

# Electronic Devices and Circuits by I. J. Nagarath, May 2010 Edition, PHI Learning Pvt. Ltd.